

**4N22****4N23****4N24**

JAN, JANTX, JANTXV, AND JANS SINGLE CHANNEL OPTOCOUPPLERS

OPTOELECTRONIC PRODUCTS  
DIVISION

01/14/2011

**Features:**

- Qualified to MIL-PRF-19500/486
- Collector in electrical contact with case
- Overall current gain: 1.5 typical (4N24)
- Base lead provided for conventional transistor biasing
- Rugged package
- High gain, high voltage transistor
- $\pm 1$  kV electrical isolation

**Applications:**

- Eliminate ground loops
- Level shifting
- Line receiver
- Switching power supplies
- Motor control

**DESCRIPTION**

A Gallium Aluminum Arsenide (GaAlAs) infrared LED and a high gain N-P-N silicon phototransistor packaged in a hermetically sealed metal case. The **4N22**, **4N23** and **4N24**'s can be tested to customer specifications.

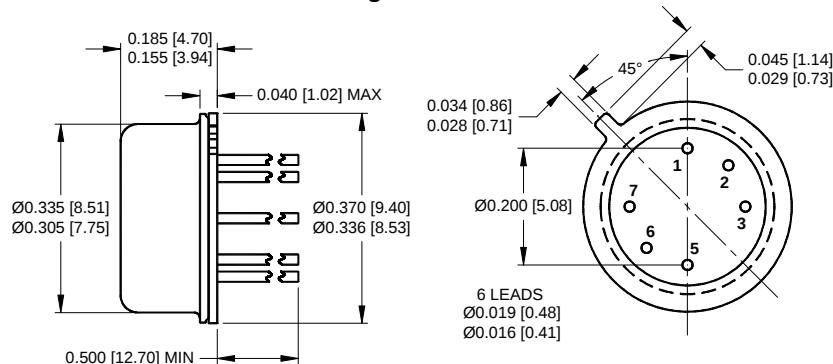
**\*ABSOLUTE MAXIMUM RATINGS**

|                                                                                                |                 |
|------------------------------------------------------------------------------------------------|-----------------|
| Input to Output Voltage .....                                                                  | $\pm 1$ kV      |
| Emitter-Collector Voltage .....                                                                | 7 V             |
| Collector-Emitter Voltage .....                                                                | 40 V            |
| Collector-Base Voltage .....                                                                   | 45 V            |
| Reverse Input Voltage .....                                                                    | 2 V             |
| Input Diode Continuous Forward Current at (or below) 25°C Free-Air Temperature (Note 1) .....  | 40mA            |
| Peak Forward Input Current (Value applies for $t_w \leq 1\mu\text{s}$ PRR < 300 pps) .....     | 1 A             |
| Continuous Collector Current .....                                                             | 50 mA           |
| Continuous Transistor Power Dissipation at (or below) 25°C Free-Air Temperature (Note 2) ..... | 300 mW          |
| Storage Temperature .....                                                                      | -65°C to +125°C |
| Operating Free-Air Temperature Range .....                                                     | -55°C to +125°C |
| Lead Solder Temperature (10 seconds max., 1/16" from case) .....                               | 240°C           |

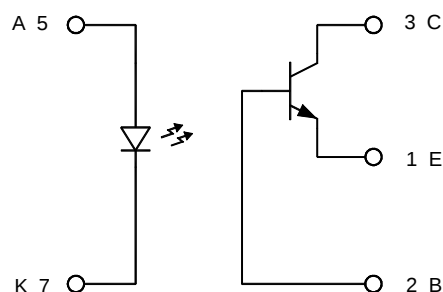
**Notes:**

1. Derate linearly to 125°C free-air temperature at the rate of 0.40 mA/°C above 65°C.
2. Derate linearly to 125°C free-air temperature at the rate of 5 mW/°C above 65°C.

- JEDEC registered data

**Package Dimensions**

ALL LINEAR DIMENSIONS ARE IN INCHES [MILLIMETERS].

**Schematic Diagram**

COLLECTOR IS COMMON TO CASE.

**4N22, 4N23, and 4N24****JAN, JANTX, JANTXV, AND JANS SINGLE CHANNEL OPTOCOUPLEDERS**

01/14/2011

**\*ELECTRICAL CHARACTERISTICS INPUT LED**  $T_A = 25^\circ\text{C}$  Unless otherwise specified

| PARAMETER                          | SYMBOL | MIN | MAX | UNITS | TEST CONDITIONS      | NOTE |
|------------------------------------|--------|-----|-----|-------|----------------------|------|
| Input Diode Static Reverse Current | $I_R$  |     | 100 | nA    | $V_R = 2\text{ V}$   |      |
| Input Diode Static Forward Voltage | $V_F$  | 1   | 1.7 | V     | $I_F = 10\text{ mA}$ |      |
| -55°C                              |        | 0.8 | 1.5 |       |                      |      |
| +25°C                              |        | 0.7 | 1.3 |       |                      |      |
| +125°C                             |        |     |     |       |                      |      |

**\*OUTPUT TRANSISTOR**  $T_A = 25^\circ\text{C}$  Unless otherwise specified

| PARAMETER                           | SYMBOL        | MIN | MAX | UNITS | TEST CONDITIONS                                        | NOTE |
|-------------------------------------|---------------|-----|-----|-------|--------------------------------------------------------|------|
| Collector-Base Breakdown Voltage    | $V_{(BR)CBO}$ | 45  |     | V     | $I_C = 100\text{ }\mu\text{A}$ , $I_E = 0$ , $I_F = 0$ |      |
| Collector-Emitter Breakdown Voltage | $V_{(BR)CEO}$ | 40  |     | V     | $I_C = 1\text{ mA}$ , $I_B = 0$ , $I_F = 0$            |      |
| Emitter-Base Breakdown Voltage      | $V_{(BR)EBO}$ | 7   |     | V     | $I_B = 0$ , $I_E = 100\text{ }\mu\text{A}$ , $I_F = 0$ |      |

**\*COUPLED CHARACTERISTICS**  $T_A = 25^\circ\text{C}$  Unless otherwise specified

| PARAMETER                            | SYMBOL        | MIN       | MAX | UNITS         | TEST CONDITIONS                                                           | NOTE |
|--------------------------------------|---------------|-----------|-----|---------------|---------------------------------------------------------------------------|------|
| On State Collector Current           | $I_{C(ON)}$   | 0.15      |     | mA            | $V_{CE} = 5\text{ V}$ , $I_B = 0$ , $I_F = 2\text{ mA}$                   |      |
| 4N22                                 |               | 0.2       |     |               |                                                                           |      |
| 4N23                                 |               | 0.4       |     |               |                                                                           |      |
| 4N24                                 |               |           |     |               |                                                                           |      |
| On State Collector Current           | $I_{C(ON)}$   | 2.5       |     | mA            | $V_{CE} = 5\text{ V}$ , $I_B = 0$ , $I_F = 10\text{ mA}$                  |      |
| 4N22                                 |               | 6         |     |               |                                                                           |      |
| 4N23                                 |               | 10        |     |               |                                                                           |      |
| 4N24                                 |               |           |     |               |                                                                           |      |
| On State Collector Current           | $I_{C(ON)}$   | 1         |     | mA            | $V_{CE} = 5\text{ V}$ , $I_B = 0$ , $I_F = 10\text{ mA}$                  |      |
| -55°C                                |               | 2.5       |     |               |                                                                           |      |
| 4N22                                 |               | 4         |     |               |                                                                           |      |
| 4N23                                 |               |           |     |               |                                                                           |      |
| 4N24                                 |               |           |     |               |                                                                           |      |
| On State Collector Current           | $I_{C(ON)}$   | 1         |     | mA            | $V_{CE} = 5\text{ V}$ , $I_B = 0$ , $I_F = 10\text{ mA}$                  |      |
| +100°C                               |               | 2.5       |     |               |                                                                           |      |
| 4N22                                 |               | 4         |     |               |                                                                           |      |
| 4N23                                 |               |           |     |               |                                                                           |      |
| 4N24                                 |               |           |     |               |                                                                           |      |
| Off State Collector Current          | $I_{C(OFF)}$  |           | 100 | nA            | $V_{CE} = 20\text{ V}$ , $I_B = 0$ , $I_F = 0\text{ mA}$                  |      |
| +25°C                                |               |           |     |               |                                                                           |      |
| Off State Collector Current          | $I_{C(OFF)}$  |           | 100 | $\mu\text{A}$ | $V_{CE} = 20\text{ V}$ , $I_B = 0$ , $I_F = 0\text{ mA}$                  |      |
| +100°C                               |               |           |     |               |                                                                           |      |
| Collector-Emitter Saturation Voltage | $V_{CE(SAT)}$ |           | 0.3 | V             | $I_C = 2.5\text{ mA}$ , $I_B = 0$ , $I_F = 20\text{ mA}$                  |      |
| 4N22                                 |               |           | 0.3 | V             | $I_C = 5\text{ mA}$ , $I_B = 0$ , $I_F = 20\text{ mA}$                    |      |
| 4N23                                 |               |           | 0.3 | V             | $I_C = 10\text{ mA}$ , $I_B = 0$ , $I_F = 20\text{ mA}$                   |      |
| 4N24                                 |               |           |     |               |                                                                           |      |
| Input to Output Resistance           | $R_{I-O}$     | $10^{11}$ |     | $\Omega$      | $V_{IN-OUT} = 1\text{ kV}$                                                | 1    |
| Input to Output Capacitance          | $C_{I-O}$     |           | 5   | pF            | $F = 1\text{ MHz}$ , $V_{IN-OUT} = 1\text{ kV}$                           | 1    |
| Rise Time                            | $t_r$         |           | 15  | $\mu\text{s}$ | $V_{CC} = 10\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 100\text{ }\Omega$ |      |
| 4N22                                 |               |           | 15  |               |                                                                           |      |
| 4N23                                 |               |           | 20  |               |                                                                           |      |
| 4N24                                 |               |           |     |               |                                                                           |      |
| Fall Time                            | $t_f$         |           | 15  | $\mu\text{s}$ | $V_{CC} = 10\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 100\text{ }\Omega$ |      |
| 4N22                                 |               |           | 15  |               |                                                                           |      |
| 4N23                                 |               |           | 20  |               |                                                                           |      |
| 4N24                                 |               |           |     |               |                                                                           |      |

**NOTES:**

- These parameters are measured between all phototransistor leads shorted together and with both input diode leads shorted together.

**RECOMMENDED OPERATING CONDITIONS:**

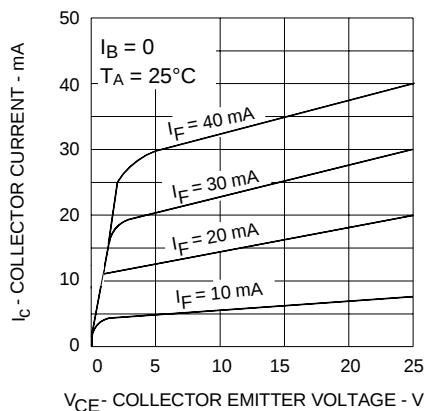
| PARAMETER                 | SYMBOL   | MIN | MAX | UNITS         |
|---------------------------|----------|-----|-----|---------------|
| Input Current, Low Level  | $I_{FL}$ | 0   | 1   | $\mu\text{A}$ |
| Input Current, High Level | $I_{FH}$ | 2   | 10  | mA            |
| Supply Voltage            | $V_{CC}$ | 5   | 10  | V             |

**SELECTION GUIDE**

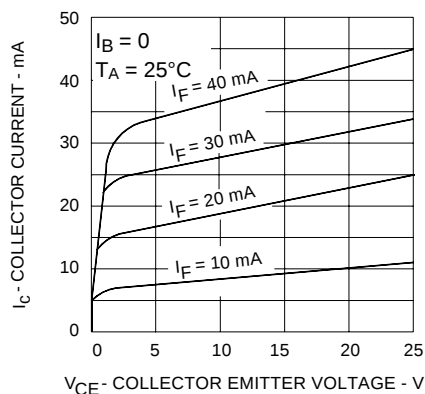
| PART NUMBER | PART DESCRIPTION |
|-------------|------------------|
| 4N22        | Commercial       |
| 4N23        | Commercial       |
| 4N24        | Commercial       |
| JAN4N22     | JAN Screened     |
| JAN4N23     | JAN Screened     |
| JAN4N24     | JAN Screened     |
| JANTX4N22   | JANTX Screened   |
| JANTX4N23   | JANTX Screened   |
| JANTX4N24   | JANTX Screened   |
| JANTXV4N22  | JANTXV Screened  |
| JANTXV4N23  | JANTXV Screened  |
| JANTXV4N24  | JANTXV Screened  |
| JANS4N22    | JANS Screened    |
| JANS4N23    | JANS Screened    |
| JANS4N24    | JANS Screened    |

\* JEDEC registered

**4N22**  
COLLECTOR CURRENT  
VS  
COLLECTOR-EMITTER VOLTAGE



**4N23**  
COLLECTOR CURRENT  
VS  
COLLECTOR-EMITTER VOLTAGE



**4N24**  
COLLECTOR CURRENT  
VS  
COLLECTOR-EMITTER VOLTAGE

